

L Number	Hits	Search Text	DB	Time stamp
1	2	("5500750").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 17:35
5	1186	(349/113).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 17:43
6	3834	349/\$.ccls. and density	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:32
7	80	349/\$.ccls. and density and permeation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:44
8	1		USPAT	2004/01/22 18:34
9	1		USPAT	2004/01/22 18:34
10	1		USPAT	2004/01/22 18:34
11	1		USPAT	2004/01/22 18:35
12	1		USPAT	2004/01/22 18:35
13	1		USPAT	2004/01/22 18:35
14	1		USPAT	2004/01/22 18:35
15	1		USPAT	2004/01/22 18:36
16	1		USPAT	2004/01/22 18:36
17	1		USPAT	2004/01/22 18:36
18	28	349/\$.ccls. and (density with barrier)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:45
19	22	(349/\$.ccls. and (density with barrier)) not (349/\$.ccls. and density and permeation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:47
20	79	349/\$.ccls. and (coating with density)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:47
21	73	(349/\$.ccls. and (coating with density)) not (349/\$.ccls. and density and permeation)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 18:54
22	34	((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:00

23	5916	((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:00
24	350	((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and "liquid crystal"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:06
25	316	((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and "liquid crystal") not ((349/\$.ccls. and density and permeation) (349/\$.ccls. and (density with barrier)) (349/\$.ccls. and (coating with density)) ((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and 349/\$.ccls.))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:04
27	204	((silicon adj (nitride oxide)) with density) ((aluminum adj oxide) with density)) and (g adj3 (cm cc))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:09
28	119	((silicon adj (nitride oxide)) with (g adj3 (cm cc))) ((aluminum adj oxide) with (g adj3 (cm cc)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:39
29	61	((silicon adj (oxide)) with (g adj3 (cm cc))) ((aluminum adj oxide) with (g adj3 (cm cc)))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:39
30	421	(349/158.ccls. 349/113.ccls.) and (sio sin alo "silicon nitride" "silicon oxide" "aluminum oxide")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 19:47
31	0	(polycarbonate with substrate) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 20:05
32	400	(polycarbonate with substrate) and 349/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/01/22 20:06